

# ELEC 404 Formula Sheet

## Basic Concepts in RF Design

Signal power in dBm:

$$P_{sig|dBm} = 10 \log \left( \frac{P_{sig}}{1 \text{ mW}} \right)$$

## Non-Linearity

Peak 1-dB compression point:

$$P_{1dB} = \sqrt{0.145 \left| \frac{\alpha_1}{\alpha_3} \right|}$$

Input Third Intercept Point:

$$A_{IIP3} = \sqrt{\frac{4}{3} \left| \frac{\alpha_1}{\alpha_3} \right|}$$

$$\frac{A_{IIP3}}{P_{1dB}} \approx 9.6 \text{ dB}$$

Cascaded Non-Linear Stages:

$$A_{IIP3} = \sqrt{\frac{4}{3} \left| \frac{\alpha_1 \beta_1}{\alpha_3 \beta_1 + 2\alpha_1 \alpha_2 \beta_2 + \alpha_1^3 \beta_3} \right|}$$

$$\frac{1}{A_{IIP3}^2} = \left| \frac{1}{A_{IIP3,1}^2} + \frac{3\alpha_2 \beta_2}{2\beta_1} + \frac{\alpha_1^2}{A_{IIP3,2}^2} \right|$$

$$\frac{1}{A_{IIP3}^2} \approx \frac{1}{A_{IIP3,1}^2} + \frac{\alpha_1^2}{A_{IIP3,2}^2} + \frac{\alpha_1^2 \beta_1^2}{A_{IIP3,3}^2} + \dots$$

## Noise

Output Spectrum of a linear, time invariant system:

$$S_y(f) = S_x(f) |H(f)|^2$$

Resistor Noise Power Spectral Density:

$$\overline{V_n^2} = 4kTR \quad \overline{I_n^2} = 4kTR$$

MOSFET Noise Power Spectral Density ( $\gamma \approx 2/3$ ):

$$\overline{V_n^2} = 4kT\gamma/g_m \quad \overline{V_n^2} = 4kT\gamma g_m$$

MOSFET 1/f noise corner frequency for some process constant  $K$ :

$$f_c = \frac{K}{WLC_{ox}} \frac{g_m}{4kT\gamma}$$

Noise Figure:

$$NF = \frac{SNR_{in}}{SNR_{out}} \quad NF_{dB} = 10 \log \left( \frac{SNR_{in}}{SNR_{out}} \right)$$

Attenuation Factor:

$$\alpha = \frac{Z_{in}}{Z_{in} + R_S}$$

Noise figure as the total noise at the output divided by the noise at the output due to the source impedance ( $\overline{V_n^2}$  is the output noise of device):

$$NF = \frac{1}{V_{RS}^2} \cdot \frac{\overline{V_{RS}^2} |\alpha|^2 A_v^2 + \overline{V_n^2}}{|\alpha|^2 A_v^2} = 1 + \frac{\overline{V_n^2}}{|\alpha|^2 A_v^2} \cdot \frac{1}{V_{RS}^2}$$

Available power gain:

$$A_P = \frac{\text{Power delivered to a matched load by stage}}{\text{Power delivered to a matched load by source}}$$

Noise figure of cascaded stages (Friis' Equation):

$$NF_{tot} = 1 + (NF_1 - 1) + \frac{NF_2 - 1}{A_{P1}} + \dots + \frac{NF_m - 1}{A_{P1} \dots A_{P(m-1)}}$$

## Passive Impedance Transformation

Capacitor Quality Factor:

$$Q_S = \frac{1}{R_S C \omega} \quad Q_P = \frac{R_P C \omega}{1}$$

Inductor Quality Factor:

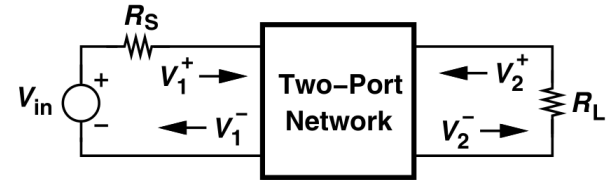
$$Q_S = \frac{L \omega}{R_S} \quad Q_P = \frac{R_P}{L \omega}$$

Series to Parallel Conversion ( $Q_P = Q_S$ ):

$$R_P = (Q_S^2 + 1) R_S$$

$$C_P = \left( \frac{Q_S^2}{Q_S^2 + 1} \right) C_S \quad L_P = \left( \frac{Q_S^2 + 1}{Q_S^2} \right) L_S$$

## Scattering Parameters



$$V_1^- = S_{11} V_1^+ + S_{12} V_2^+$$

$$V_2^- = S_{21} V_1^+ + S_{22} V_2^+$$

Accuracy of input matching:

$$S_{11} = \frac{V_1^-}{V_1^+} |_{V_2^+=0} \approx \frac{Z_{in} - R_S}{Z_{in} + R_S}$$

Reverse isolation:

$$S_{12} = \frac{V_1^-}{V_2^+} |_{V_1^+=0}$$

Accuracy of output matching:

$$S_{22} = \frac{V_2^-}{V_2^+} |_{V_1^+=0} \approx \frac{Z_{out} - R_S}{Z_{out} + R_S}$$

Circuit gain:

$$S_{21} = \frac{V_2^-}{V_1^+} |_{V_2^+=0}$$

Scattering parameters in dB:

$$S_{mn|dB} = 20 \log |S_{mn}|$$

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<https://github.com/DonneyF/formula-sheets>